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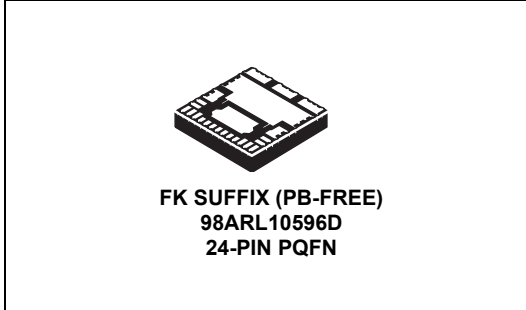
Quad high-side switch (quad 35 mOhm)

The 35XS3400 is one in a family of devices designed for low-voltage automotive lighting applications. Its four low $R_{DS(on)}$ MOSFETs (quad 35 mOhm) can control four separate 28 W bulbs, and/or LEDs.

Programming, control and diagnostics are accomplished using a 16-bit SPI interface. Its output with selectable slew rate improves electromagnetic compatibility (EMC) behavior. Additionally, each output has its own parallel input or SPI control for pulse-width modulation (PWM) control. The 35XS3400 allows the user to program via the SPI the fault current trip levels and duration of acceptable lamp inrush. The device has Fail-safe mode to provide functionality of the outputs in case of MCU damage. This device is powered by SMARTMOS technology.

35XS3400

HIGH-SIDE SWITCH



Features

- Four protected 35 mΩ high-side switches (at 25 °C)
- Operating voltage range of 6.0 V to 20 V with standby current < 5.0 μA, extended mode from 4.0 V to 28 V
- 8.0 MHz 16-bit 3.3 V and 5.0 V SPI control and status reporting with daisy chain capability
- PWM module using external clock or calibratable internal oscillator with programmable outputs delay management
- Smart overcurrent shutdown, severe short-circuit, overtemperature protection with time limited autoretry, and Fail-safe mode in case of MCU damage
- Output OFF or ON openload detection compliant to bulbs or LEDs and short to battery detection
- Analog current feedback with selectable ratio and board temperature feedback

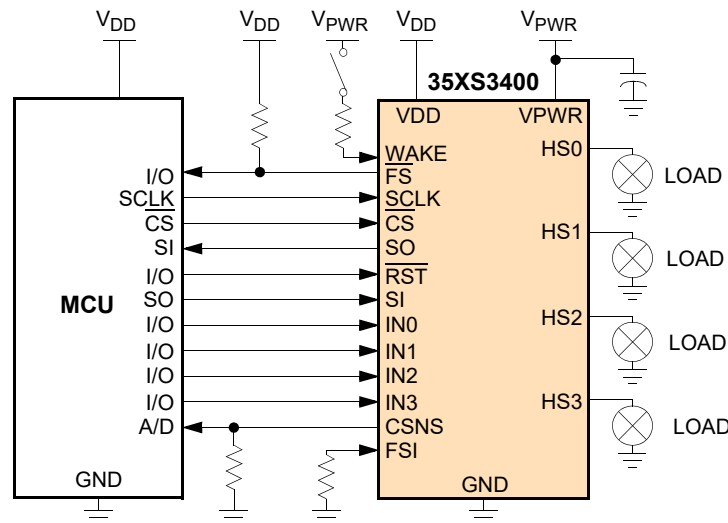


Figure 1. 35XS3400 simplified application diagram



Table of Contents

1	Orderable parts	3
2	Device variations	3
3	Internal block diagram	4
4	Pin connections	5
5	Electrical characteristics	7
5.1	Maximum ratings	7
5.2	Static electrical characteristics	8
5.3	Dynamic electrical characteristics	12
5.4	Timing diagrams	17
6	Functional description	20
6.1	Introduction	20
6.2	Functional pin description	20
6.3	Functional internal block description	22
7	Functional device operation	23
7.1	SPI protocol description	23
7.2	Operational modes	23
7.3	Protection and diagnostic features	28
7.4	Logic commands and registers	32
8	Typical applications	41
9	Packaging	42
9.1	Soldering information	42
9.2	Package dimensions	43
10	Additional documentation	47
10.1	Thermal addendum (Rev 2.0)	47
11	Revision history	52

1 Orderable parts

This section describes the part numbers available to be purchased along with their differences. Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to <http://www.nxp.com> and perform a part number search for the following device numbers.

Table 1. Orderable part variations

Part number ⁽¹⁾	Temperature (T _A)	Package
MC35XS3400CHFK	-40 °C to 125 °C	24-pin PQFN
MC35XS3400DHFK		

Notes

- To order parts in tape and reel, add the R2 suffix to the part number.

2 Device variations

Table 2. Device variations

Characteristic	Symbol	Min	Typ	Max	Unit
Wake input clamp voltage, I _{CL(WAKE)} < 2.5 mA <ul style="list-style-type: none"> 35XS3400CHFK 35XS3400DHFK 	V _{CL(WAKE)}	18 20	25 27	32 35	V
Fault detection blanking time <ul style="list-style-type: none"> 35XS3400CHFK 35XS3400DHFK 	t _{FAULT}	- -	5.0 5.0	20 10	μs
Output shutdown delay time <ul style="list-style-type: none"> 35XS3400CHFK 35XS3400DHFK 	t _{DETECT}	- -	7.0 7.0	30 20	μs
Openload detection time in OFF state ⁽²⁾ <ul style="list-style-type: none"> 35XS3400CHFK and 35XS3400DHFK 	t _{OLOFF}	170	212	270	μs
Peak Package Reflow Temperature During Reflow ^{(3), (4)}	T _{PPRT}	Note 4			°C

Notes

- Guaranteed by design.
- Pin soldering temperature limit is for 40 seconds maximum duration. Not designed for immersion soldering. Exceeding these limits may cause malfunction or permanent damage to the device.
- NXP's Package Reflow capability meets Pb-free requirements for JEDEC standard J-STD-020C. For Peak Package Reflow Temperature and Moisture Sensitivity Levels (MSL), go to www.nxp.com, search by part number (remove prefixes/suffixes) and enter the core ID to view all orderable parts, and review parametrics.

3 Internal block diagram

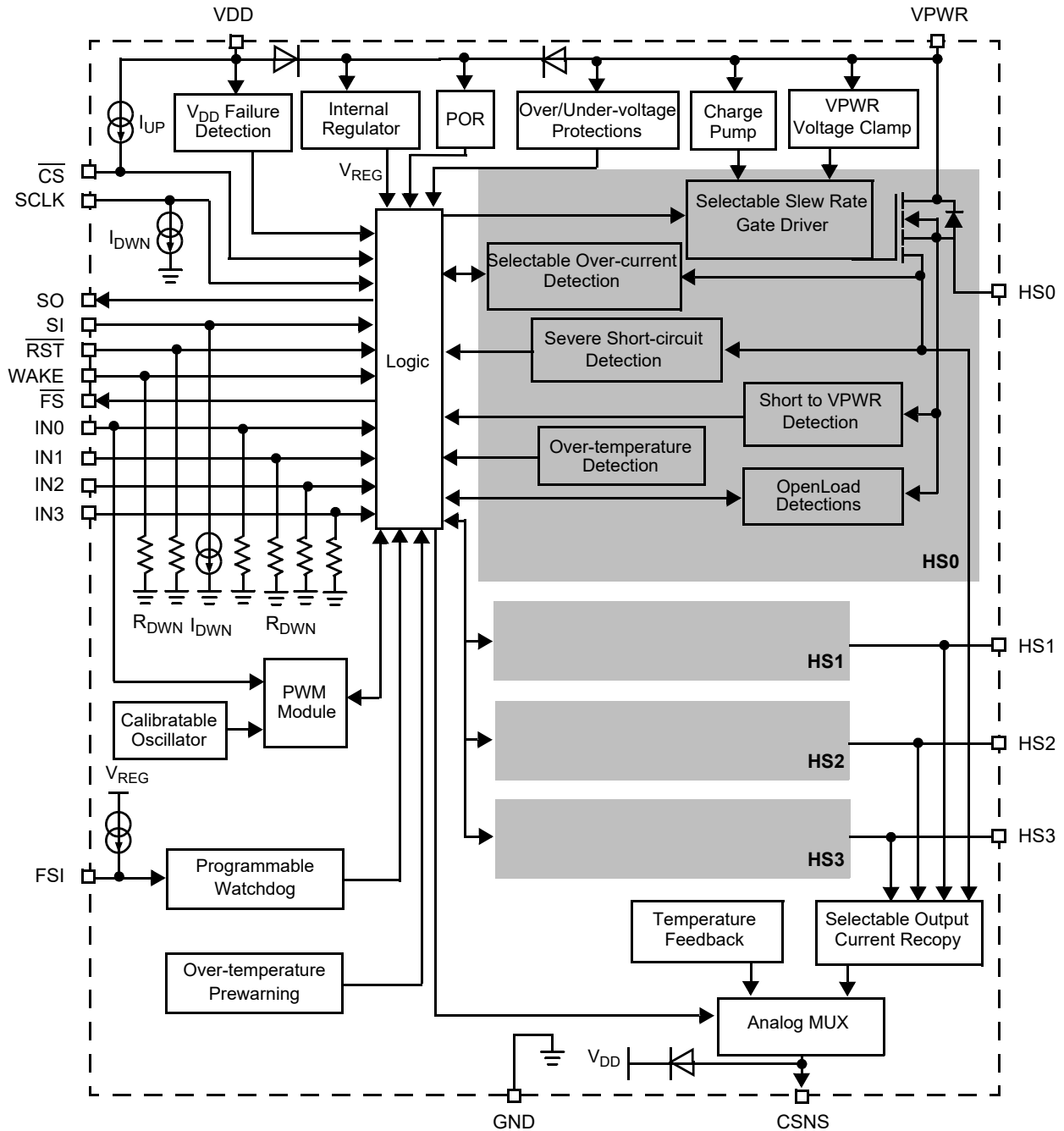


Figure 2. 35XS3400 simplified internal block diagram

4 Pin connections

Transparent Top View of Package

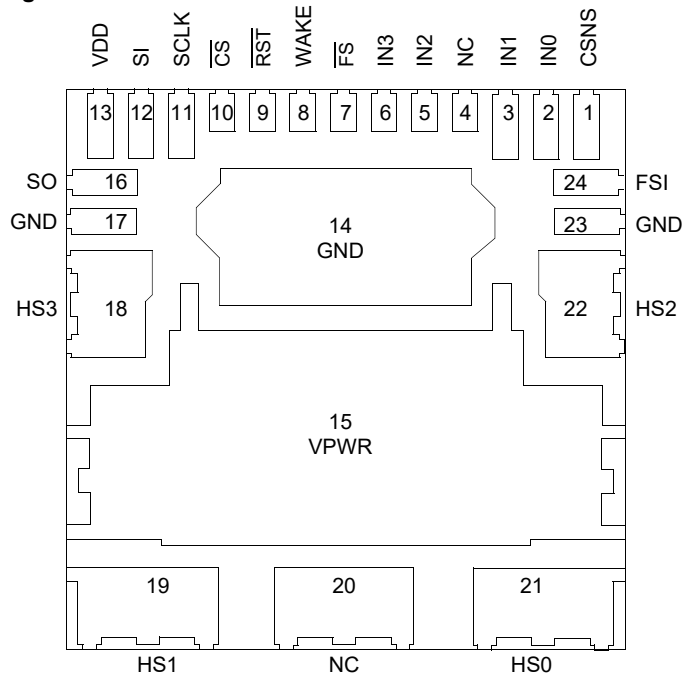


Figure 3. 35XS3400 pin connections

Table 3. 35XS3400 pin definitions

A functional description of each pin can be found in the Functional Pin Description section beginning on page 20.

Pin number	Pin name	Pin function	Formal name	Definition
1	CSNS	Output	Output current monitoring	This pin reports an analog value proportional to the designated HS[0:3] output current or the temperature of the GND flag (pin 14). It is used externally to generate a ground-referenced voltage for the microcontroller (MCU). Current recopy and temperature feedback is SPI programmable.
2 3 5 6	IN0 IN1 IN2 IN3	Input	Direct inputs	Each direct input controls the device mode. The IN[0:3] high-side input pins are used to directly control HS0:HS3 high-side output pins. The PWM frequency can be generated from IN0 pin to PWM module in case the external clock is set.
7	\overline{FS}	Output	Fault status (active low)	This pin is an open drain configured output requiring an external pull-up resistor to V_{DD} for fault reporting.
8	WAKE	Input	Wake	This input pin controls the device mode.
9	\overline{RST}	Input	Reset	This input pin is used to initialize the device configuration and fault registers, as well as place the device in a low-current Sleep mode.
10	\overline{CS}	Input	Chip Select (active low)	This input pin is connected to a chip select output of a master microcontroller (MCU).
11	SCLK	Input	Serial clock	This input pin is connected to the MCU providing the required bit shift clock for SPI communication.
12	SI	Input	Serial input	This pin is a command data input pin connected to the SPI serial data output of the MCU or to the SO pin of the previous device of a daisy-chain of devices.
13	VDD	Power	Digital drain voltage	This pin is an external voltage input pin used to supply power interfaces to the SPI bus.

Table 3. 35XS3400 pin definitions (continued)

A functional description of each pin can be found in the Functional Pin Description section beginning on page [20](#).

Pin number	Pin name	Pin function	Formal name	Definition
14, 17, 23	GND	Ground	Ground	These pins, internally shorted, are the ground for the logic and analog circuitry of the device. These ground pins must be also shorted in the board.
15	VPWR	Power	Positive power supply	This pin connects to the positive power supply and is the source of operational power for the device.
16	SO	Output	Serial output	This output pin is connected to the SPI serial data input pin of the MCU or to the SI pin of the next device of a daisy-chain of devices.
18 19 21 22	HS3 HS1 HS0 HS2	Output	High-side outputs	Protected 35 mΩ high-side power output pins to the load.
4, 20	NC	N/A	No connect	These pins may not be connected.
24	FSI	Input	Fail-safe input	This input enables the watchdog timeout feature.

5 Electrical characteristics

5.1 Maximum ratings

Table 4. Maximum ratings

All voltages are with respect to ground unless otherwise noted. Exceeding these ratings may cause a malfunction or permanent damage to the device.

Ratings	Symbol	Value	Unit
ELECTRICAL RATINGS			
V _{PWR} supply voltage range <ul style="list-style-type: none"> • Load dump at 25 °C (400 ms) • Maximum operating voltage • Reverse battery at 25 °C (2.0 min.) 	V _{PWR(SS)}	41 28 -18	V
V _{DD} supply voltage range	V _{DD}	-0.3 to 5.5	V
Input/output voltage	(8)	-0.3 to V _{DD} +0.3	V
WAKE input clamp current	I _{CL(WAKE)}	2.5	mA
CSNS input clamp current	I _{CL(CSNS)}	2.5	mA
HS [0:3] voltage <ul style="list-style-type: none"> • Positive • Negative 	V _{HS[0:3]}	41 -16	V
Output current ⁽⁵⁾	I _{HS[0:3]}	6	A
Output clamp energy using single-pulse method ⁽⁶⁾	E _{CL[0:3]}	35	mJ
ESD voltage ⁽⁷⁾ <ul style="list-style-type: none"> • Human Body Model (HBM) for HS[0:3], VPWR and GND • Human Body Model (HBM) for other pins • Charge Device Model (CDM) <ul style="list-style-type: none"> Corner pins (1, 13, 19, 21) All other pins (2-12, 14-18, 20, 22-24) 	V _{ESD1} V _{ESD2} V _{ESD3} V _{ESD4}	±8000 ±2000 ±750 ±500	V
THERMAL RATINGS			
Operating temperature <ul style="list-style-type: none"> • Ambient • Junction 	T _A T _J	-40 to 125 -40 to 150	°C
Storage Temperature	T _{STG}	-55 to 150	°C
THERMAL RESISTANCE			
Thermal resistance ⁽⁹⁾ <ul style="list-style-type: none"> • Junction to Case • Junction to Ambient 	R _{θJC} R _{θJA}	<1.0 30	°C/W
Peak Package Reflow Temperature During Reflow ^{(10), (11)}	T _{PPRT}	Note 11	°C

Notes

- Continuous high-side output current rating so long as maximum junction temperature is not exceeded. Calculation of maximum output current using package thermal resistance is required.
- Active clamp energy using single-pulse method (L = 2.0 mH, R_L = 0 Ω, V_{PWR} = 14 V, T_J = 150 °C initial).
- ESD testing is performed in accordance with the Human Body Model (HBM) (C_{ZAP} = 100 pF, R_{ZAP} = 1500 Ω), the Machine Model (MM) (C_{ZAP} = 200 pF, R_{ZAP} = 0 Ω), and the Charge Device Model (CDM), Robotic (C_{ZAP} = 4.0 pF).
- Input / Output pins are: IN[0:3], RST, FSI, CSNS, SI, SCLK, CS, SO, FS
- Device mounted on a 2s2p test board per JEDEC JESD51-2. 15 °C/W of R_{θJA} can be reached in a real application case (4 layers board).
- Pin soldering temperature limit is for 40 seconds maximum duration. Not designed for immersion soldering. Exceeding these limits may cause malfunction or permanent damage to the device.
- NXP's Package Reflow capability meets Pb-free requirements for JEDEC standard J-STD-020C. For Peak Package Reflow Temperature and Moisture Sensitivity Levels (MSL), go to www.nxp.com, search by part number (remove prefixes/suffixes) and enter the core ID to view all orderable parts, and review parametrics.

5.2 Static electrical characteristics

Table 5. Static electrical characteristics

Characteristics noted under conditions $6.0\text{ V} \leq V_{PWR} \leq 20\text{ V}$, $3.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $-40\text{ }^\circ\text{C} \leq T_A \leq 125\text{ }^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_A = 25\text{ }^\circ\text{C}$ under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
POWER INPUTS					
Battery supply voltage range • Fully operational • Extended mode ⁽¹²⁾	V_{PWR}	6.0 4.0	– –	20 28	V
Battery clamp voltage ⁽¹³⁾	$V_{PWR(\text{CLAMP})}$	41	47	53	V
V_{PWR} operating supply current • Outputs commanded ON, HS[0:3] open, IN[0:3] > V_{IH}	$I_{PWR(\text{ON})}$	–	6.5	20	mA
V_{PWR} supply current • Outputs commanded OFF, OFF openload detection disabled, HS[0:3] shorted to the ground with $V_{DD} = 5.5\text{ V}$ WAKE > V_{IH} or $\overline{\text{RST}} > V_{IH}$ and IN[0:3] < V_{IL}	$I_{PWR(\text{SBY})}$	–	6.0	8.0	mA
Sleep state supply current $V_{PWR} = 12\text{ V}$, $\overline{\text{RST}} = \text{WAKE} = \text{IN}[0:3] < V_{IL}$, HS[0:3] shorted to the ground • $T_A = 25\text{ }^\circ\text{C}$ • $T_A = 85\text{ }^\circ\text{C}$	$I_{PWR(\text{SLEEP})}$	– –	1.0 –	5.0 30	μA
V_{DD} supply voltage	$V_{DD(\text{ON})}$	3.0	–	5.5	V
V_{DD} supply current at $V_{DD} = 5.5\text{ V}$ • No SPI communication • 8.0 MHz SPI communication ⁽¹⁴⁾	$I_{DD(\text{ON})}$	– –	1.6 5.0	2.2 –	mA
V_{DD} sleep state current at $V_{DD} = 5.5\text{ V}$	$I_{DD(\text{SLEEP})}$	–	–	5.0	μA
Overvoltage shutdown threshold	$V_{PWR(\text{OV})}$	28	32	36	V
Overvoltage shutdown hysteresis	$V_{PWR(\text{OVHYS})}$	0.2	0.8	1.5	V
Undervoltage shutdown threshold ⁽¹⁵⁾	$V_{PWR(\text{UV})}$	3.3	3.9	4.3	V
V_{PWR} and V_{DD} power on reset threshold	$V_{\text{SUPPLY}(\text{POR})}$	0.5	–	0.9	$V_{PWR(\text{UV})}$
V_{DD} supply failure threshold (for $V_{PWR} > V_{PWR(\text{UV})}$)	$V_{DD(\text{FAIL})}$	2.2	2.5	2.8	V
Recovery undervoltage threshold	$V_{PWR(\text{UV})_UP}$	3.4	4.1	4.5	V
OUTPUTS HS0 TO HS3					
Output Drain-to-Source ON resistance ($I_{HS} = 2.0\text{ A}$, $T_A = 25\text{ }^\circ\text{C}$) • $V_{PWR} = 4.0\text{ V}$ • $V_{PWR} = 6.0\text{ V}$ • $V_{PWR} = 10\text{ V}$ • $V_{PWR} = 13\text{ V}$	$R_{DS(\text{ON})_25}$	– – – –	– – – –	100 55 35 35	$\text{m}\Omega$

Notes

12. In extended mode, the functionality is guaranteed but not the electrical parameters. From 4.0 to 6.0 V voltage range, the device is only protected with the thermal shutdown detection.
13. Measured with the outputs open.
14. Typical value guaranteed per design.
15. Output will automatically recover with time limited autoretry to instructed state when V_{PWR} voltage is restored to normal as long as the V_{PWR} degradation level did not go below the under-voltage power-ON reset threshold. This applies to all internal device logic that is supplied by V_{PWR} and assumes that the external V_{DD} supply is within specification.

Table 5. Static electrical characteristics (continued)

Characteristics noted under conditions $6.0\text{ V} \leq V_{PWR} \leq 20\text{ V}$, $3.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $-40\text{ }^\circ\text{C} \leq T_A \leq 125\text{ }^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_A = 25\text{ }^\circ\text{C}$ under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
OUTPUTS HS0 TO HS3 (continued)					
Output Drain-to-Source ON resistance ($I_{HS} = 2.0\text{ A}$, $T_A = 150\text{ }^\circ\text{C}$) <ul style="list-style-type: none"> $V_{PWR} = 4.5\text{ V}$ $V_{PWR} = 6.0\text{ V}$ $V_{PWR} = 10\text{ V}$ $V_{PWR} = 13\text{ V}$ 	$R_{DS(ON)_150}$	– – – –	– – – –	170 94 66 66	$\text{m}\Omega$
Output Source-to-Drain ON resistance ($I_{HS} = -2.0\text{ A}$, $V_{PWR} = -18\text{ V}$) ⁽¹⁶⁾ <ul style="list-style-type: none"> $T_A = 25\text{ }^\circ\text{C}$ $T_A = 150\text{ }^\circ\text{C}$ 	$R_{SD(ON)}$	– –	– –	52.5 70	$\text{m}\Omega$
Maximum severe short-circuit impedance detection ⁽¹⁷⁾	R_{SHORT}	70	160	200	$\text{m}\Omega$
Output overcurrent detection levels ($6.0\text{ V} \leq V_{HS[0:3]} \leq 20\text{ V}$)	OCHI1_0 OCHI2_0 OC1_0 OC2_0 OC3_0 OC4_0 OCLO4_0 OCLO3_0 OCLO2_0 OCLO1_0	39.5 25.2 22 18.9 15.7 12.6 9.4 6.3 5.0 3.2	47 30 26.2 22.5 18.7 15 11.2 7.5 6.0 4.0	54.5 34.8 30.4 26.1 21.7 17.4 13.0 8.7 7.0 4.8	A
C_{SR0} current recopy accuracy with one calibration point ($6.0\text{ V} \leq V_{HS[0:3]} \leq 20\text{ V}$) ⁽¹⁹⁾ <ul style="list-style-type: none"> Output current 2.0 A 	$C_{SR0_0_ACC(CAL)}$	-5.0	–	5.0	%
Current sense ratio ($6.0\text{ V} \leq V_{HS[0:3]} \leq 20\text{ V}$, $CSNS \leq 5.0\text{ V}$) ⁽¹⁸⁾ <ul style="list-style-type: none"> $CSNS_ratio$ bit = 0 $CSNS_ratio$ bit = 1 	C_{SR0_0} C_{SR1_0}	– –	1/4300 1/25800	– –	–
Current sense ratio (C_{SR0}) accuracy ($6.0\text{ V} \leq V_{HS[0:3]} \leq 20\text{ V}$) <ul style="list-style-type: none"> Output current 6.75 A 2.5 A 1.5 A 0.75 A 	$C_{SR0_0_ACC}$	-12 -13 -16 -20	– – – –	12 13 16 20	%

Notes

- Source-Drain ON resistance (Reverse Drain-to-Source ON resistance) with negative polarity V_{PWR} .
- Short-circuit impedance calculated from HS[0:3] to GND pins. Value guaranteed per design.
- Current sense ratio = $I_{CSNS} / I_{HS[0:3]}$.
- Based on statistical analysis, it is not production tested.

Table 5. Static electrical characteristics (continued)

Characteristics noted under conditions $6.0\text{ V} \leq V_{PWR} \leq 20\text{ V}$, $3.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $-40\text{ }^\circ\text{C} \leq T_A \leq 125\text{ }^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_A = 25\text{ }^\circ\text{C}$ under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
OUTPUTS HS0 TO HS3 (continued)					
C_{SR0} current recopy temperature drift ($6.0\text{ V} \leq V_{HS[0:3]} \leq 20\text{ V}$) ⁽²⁰⁾ • Output Current 2.0 A	$\Delta(C_{SR0_0})/\Delta(T)$			0.04	%/ $^\circ\text{C}$
Current sense ratio (C_{SR1}) accuracy ($6.0\text{ V} \leq V_{HS[0:3]} \leq 20\text{ V}$) • Output current 6.25 A 39.5 A	$C_{SR1_0_ACC}$	-17 -12	- -	+17 +12	%
Current sense clamp voltage • CSNS Open; $I_{HS[0:3]} = 2.0\text{ A}$ with C_{SR0} ratio	$V_{CL(CSNS)}$	$V_{DD}+0.25$	-	$V_{DD}+1.0$	V
OFF openload detection source current ⁽²¹⁾	$I_{OLD(OFF)}$	30	-	100	μA
OFF openload fault detection voltage threshold	$V_{OLD(THRES)}$	2.0	3.0	4.0	V
ON openload fault detection current threshold	$I_{OLD(ON)}$	100	300	600	mA
ON openload fault detection current threshold with LED $V_{HS[0:3]} = V_{PWR} - 0.75\text{ V}$	$I_{OLD(ON_LED)}$	2.5	5.0	10	mA
Output short to V_{PWR} detection voltage threshold Output programmed OFF	$V_{OSD(THRES)}$	$V_{PWR}-1.2$	$V_{PWR}-0.8$	$V_{PWR}-0.4$	V
Output negative clamp voltage • $0.5\text{ A} \leq I_{HS[0:3]} \leq 5.0\text{ A}$, output programmed OFF	V_{CL}	-22	-	-16	V
Output overtemperature shutdown for $4.5\text{ V} < V_{PWR} < 28\text{ V}$	T_{SD}	155	175	195	$^\circ\text{C}$

Notes

20. Based on statistical data: $\Delta(C_{SR0})/\Delta(T) = \{(\text{measured } I_{CSNS} \text{ at } T_1 - \text{measured } I_{CSNS} \text{ at } T_2) / \text{measured } I_{CSNS} \text{ at room}\} / \{T_1 - T_2\}$. No production tested.
21. Output OFF openload detection current is the current required to flow through the load for the purpose of detecting the existence of an openload condition when the specific output is commanded OFF. Pull-up current is measured for $V_{HS} = V_{OLD(THRES)}$

Table 5. Static electrical characteristics (continued)

Characteristics noted under conditions $6.0\text{ V} \leq V_{PWR} \leq 20\text{ V}$, $3.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $-40\text{ }^\circ\text{C} \leq T_A \leq 125\text{ }^\circ\text{C}$, $GND = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_A = 25\text{ }^\circ\text{C}$ under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
CONTROL INTERFACE					
Input logic high voltage ⁽²²⁾	V_{IH}	2.0	–	$V_{DD}+0.3$	V
Input logic low voltage ⁽²²⁾	V_{IL}	-0.3	–	0.8	V
Input logic pull-down current (SCLK, SI) ⁽²⁵⁾	I_{DWN}	5.0	–	20	μA
Input logic pull-up current (\overline{CS}) ⁽²⁶⁾	I_{UP}	5.0	–	20	μA
SO, \overline{FS} Tri-state capacitance ⁽²³⁾	C_{SO}	–	–	20	pF
Input logic pull-down resistor (\overline{RST} , WAKE and IN[0:3])	R_{DWN}	125	250	500	k Ω
Input capacitance ⁽²³⁾	C_{IN}	–	4.0	12	pF
Wake input clamp voltage ⁽²⁴⁾ , $I_{CL(WAKE)} < 2.5\text{ mA}$ • 35XS3400CHFK • 35XS3400DHFK	$V_{CL(WAKE)}$	18 20	25 27	32 35	V
Wake input forward voltage • $I_{CL(WAKE)} = -2.5\text{ mA}$	$V_{F(WAKE)}$	-2.0	–	-0.3	V
SO high state output voltage • $I_{OH} = 1.0\text{ mA}$	V_{SOH}	$V_{DD}-0.4$	–	–	V
SO and \overline{FS} low-state output voltage • $I_{OL} = -1.0\text{ mA}$	V_{SOL}	–	–	0.4	V
SO, CSNS and \overline{FS} tri-state leakage current • $\overline{CS} = V_{IH}$ and $0\text{ V} \leq V_{SO} \leq V_{DD}$, or $\overline{FS} = 5.5\text{ V}$, or CSNS=0.0 V	$I_{SO(LEAK)}$	-2.0	0	2.0	μA
FSI external pull-down resistance ⁽²⁷⁾ • Watchdog disabled • Watchdog enabled	RFS	– 10	0 Infinite	1.0 –	k Ω

Notes

22. Upper and lower logic threshold voltage range applies to SI, \overline{CS} , SCLK, \overline{RST} , IN[0:3] and WAKE input signals. The WAKE and \overline{RST} signals may be supplied by a derived voltage referenced to V_{PWR} .
23. Input capacitance of SI, \overline{CS} , SCLK, \overline{RST} , IN[0:3] and WAKE. This parameter is guaranteed by process monitoring but is not production tested.
24. The current must be limited by a series resistance when using voltages $> 7.0\text{ V}$.
25. Pull-down current is with $V_{SI} \geq 1.0\text{ V}$ and $V_{SCLK} \geq 1.0\text{ V}$.
26. Pull-up current is with $V_{\overline{CS}} \leq 2.0\text{ V}$. \overline{CS} has an active internal pull-up to V_{DD} .
27. In Fail-safe HS[0:3] depends respectively on ON[0:3]. FSI has an active internal pull-up to $V_{REG} \sim 3.0\text{ V}$.

5.3 Dynamic electrical characteristics

Table 6. Dynamic electrical characteristics

Characteristics noted under conditions $6.0\text{ V} \leq V_{PWR} \leq 20\text{ V}$, $3.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $-40\text{ }^\circ\text{C} \leq T_A \leq 125\text{ }^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_A = 25\text{ }^\circ\text{C}$ under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
POWER OUTPUT TIMING HS0 TO HS3					
Output rising medium slew rate (medium speed slew rate / SR[1:0]=00) ⁽²⁸⁾ • $V_{PWR} = 14\text{ V}$	SR _{R_00}	0.2	0.4	0.8	V/ μs
Output rising slow slew rate (low speed slew rate / SR[1:0]=01) ⁽²⁸⁾ • $V_{PWR} = 14\text{ V}$	SR _{R_01}	0.1	0.2	0.4	V/ μs
Output falling fast slew rate (high speed slew rate / SR[1:0]=10) ⁽²⁸⁾ • $V_{PWR} = 14\text{ V}$	SR _{R_10}	0.4	0.8	1.6	V/ μs
Output falling medium slew rate (medium speed slew rate / SR[1:0]=00) ⁽²⁸⁾ • $V_{PWR} = 14\text{ V}$	SR _{F_00}	0.2	0.4	0.8	V/ μs
Output falling slow slew rate (low speed slew rate / SR[1:0]=01) ⁽²⁸⁾ • $V_{PWR} = 14\text{ V}$	SR _{F_01}	0.1	0.2	0.4	V/ μs
Output rising fast slew rate (high speed slew rate / SR[1:0]=10) ⁽²⁸⁾ • $V_{PWR} = 14\text{ V}$	SR _{F_10}	0.4	0.8	1.6	V/ μs
Output turn-on delay time ⁽²⁹⁾ • $V_{PWR} = 14\text{ V}$ for medium speed slew rate (SR[1:0]=00)	t _{DLY(ON)}	35	60	85	μs
Output turn-off delay time ⁽³⁰⁾ • $V_{PWR} = 14\text{ V}$ for medium speed slew rate (SR[1:0]=00)	t _{DLY(OFF)}	35	60	85	μs
Driver output matching slew rate (SR _R / SR _F) $V_{PWR} = 14\text{ V}$ @ $25\text{ }^\circ\text{C}$ and for medium speed slew rate (SR[1:0]=00)	ΔSR	0.8	1.0	1.2	
Driver output matching time (t _{DLY(ON)} - t _{DLY(OFF)}) $V_{PWR} = 14\text{ V}$, $f_{\text{PWM}} = 240\text{ Hz}$, PWM duty-cycle = 50%, @ $25\text{ }^\circ\text{C}$ for medium speed slew rate (SR[1:0]=00)	Δt_{RF}	-25	0	25	μs

Notes

28. Rise and fall slew rates measured across a $5.0\ \Omega$ resistive load at high-side output = 30 % to 70 % (see [Figure 4](#), page 17).
29. Turn-on delay time measured from rising edge of any signal (IN[0:3] and $\overline{\text{CS}}$) that would turn the output ON to $V_{\text{HS}[0:3]} = V_{\text{PWR}} / 2$ with $R_L = 5.0\ \Omega$ resistive load.
30. Turn-off delay time measured from falling edge of any signal (IN[0:3] and $\overline{\text{CS}}$) that would turn the output OFF to $V_{\text{HS}[0:3]} = V_{\text{PWR}} / 2$ with $R_L = 5.0\ \Omega$ resistive load.

Table 6. Dynamic electrical characteristics (continued)

Characteristics noted under conditions $6.0\text{ V} \leq V_{PWR} \leq 20\text{ V}$, $3.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $-40\text{ }^\circ\text{C} \leq T_A \leq 125\text{ }^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_A = 25\text{ }^\circ\text{C}$ under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
POWER OUTPUT TIMING HS0 TO HS3 (continued)					
Fault detection blanking time ⁽³¹⁾ • 35XS3400CHFK • 35XS3400DHFK	t_{FAULT}	- -	5.0 5.0	20 10	μs
Output shutdown delay time ⁽³²⁾ • 35XS3400CHFK • 35XS3400DHFK	t_{DETECT}	- -	7.0 7.0	30 20	μs
$\overline{\text{CS}}$ to CSNS valid time ⁽³³⁾	t_{CNSVAL}	-	70	100	μs
Watchdog timeout ⁽³⁴⁾	t_{WDTO}	217	310	400	ms
ON openload fault cyclic detection period with LED • Internal clock (PWM_en bit = 1 & CLOCK_Set = 1) • External clock (PWM_en bit = 1 & CLOCK_Set = 0)	T_{OLLED}	6.4 -	8.3 PWM period	12 -	ms

Notes

31. Time necessary to report the fault to $\overline{\text{FS}}$ pin.
32. Time necessary to switch-off the output in case of OT or OC or SC or UV fault detection (from negative edge of $\overline{\text{FS}}$ pin to HS voltage = 50 % of V_{PWR})
33. Time necessary for the CSNS to be with $\pm 5\%$ of the targeted value.
34. For FSI open, the watchdog timeout delay measured from the rising edge of RST, to HS[0,2] output state depend on the corresponding input command.

Table 6. Dynamic electrical characteristics (continued)

Characteristics noted under conditions $6.0\text{ V} \leq V_{\text{PWR}} \leq 20\text{ V}$, $3.0\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}$, $-40\text{ }^\circ\text{C} \leq T_{\text{A}} \leq 125\text{ }^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_{\text{A}} = 25\text{ }^\circ\text{C}$ under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
Output overcurrent time step					ms
OC[1:0]=00 (slow by default)	t_{OC1_00}	3.4	5.0	6.6	
	t_{OC2_00}	1.0	1.72	2.0	
	t_{OC3_00}	1.4	2.0	2.6	
	t_{OC4_00}	2.0	3.0	4.0	
	t_{OC5_00}	3.4	5.0	6.74	
	t_{OC6_00}	8.4	12.2	16	
	t_{OC7_00}	31.2	44.6	48	
OC[1:0]=01 (fast)	t_{OC1_01}	1.72	2.48	3.22	
	t_{OC2_01}	0.56	0.8	1.04	
	t_{OC3_01}	0.72	1.04	1.36	
	t_{OC4_01}	1.02	1.58	1.92	
	t_{OC5_01}	1.56	2.24	2.92	
	t_{OC6_01}	4.28	6.12	7.96	
	t_{OC7_01}	15.4	22.2	29	
OC[1:0]=10 (medium)	t_{OC1_10}	6.8	9.8	12.8	
	t_{OC2_10}	2.2	3.2	4.2	
	t_{OC3_10}	2.8	4.2	5.6	
	t_{OC4_10}	4.0	5.8	7.6	
	t_{OC5_10}	6.8	9.8	12.8	
	t_{OC6_10}	17	24.4	31.8	
	t_{OC7_10}	6.24	89.2	116	
OC[1:0]=11 (very slow)	t_{OC1_11}	13.7	19.6	25.5	
	t_{OC2_11}	4.5	6.4	8.3	
	t_{OC3_11}	5.9	8.4	10.9	
	t_{OC4_11}	8.1	11.6	15.1	
	t_{OC5_11}	13.7	19.6	25.5	
	t_{OC6_11}	34.2	48.8	63.4	
	t_{OC7_11}	124.9	178.4	231.9	

Table 6. Dynamic electrical characteristics (continued)

Characteristics noted under conditions $6.0\text{ V} \leq V_{\text{PWR}} \leq 20\text{ V}$, $3.0\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}$, $-40\text{ }^\circ\text{C} \leq T_{\text{A}} \leq 125\text{ }^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_{\text{A}} = 25\text{ }^\circ\text{C}$ under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
Bulb cooling time step					ms
CB[1:0]=00 or 11 (medium)	t_{BC1_00}	582	834	1084	
	t_{BC2_00}	312	448	584	
	t_{BC3_00}	356	510	664	
	t_{BC4_00}	416	596	776	
	t_{BC5_00}	502	718	934	
	t_{BC6_00}	628	898	1168	
CB[1:0]=01 (fast)	t_{BC1_01}	296	418	544	
	t_{BC2_01}	156	224	292	
	t_{BC3_01}	176	254	332	
	t_{BC4_01}	202	290	378	
	t_{BC5_01}	256	360	468	
	t_{BC6_01}	452	648	884	
CB[1:0]=10 (slow)	t_{BC1_10}	1166	1668	2170	
	t_{BC2_10}	624	894	1164	
	t_{BC3_10}	714	1022	1310	
	t_{BC4_10}	834	1192	1552	
	t_{BC5_10}	1002	1434	1866	
	t_{BC6_10}	1256	1796	2340	

PWM MODULE TIMING

Input PWM clock range on IN0	f_{IN0}	7.68	–	30.72	kHz
Input PWM clock low frequency detection range on IN0 ⁽³⁵⁾	$f_{\text{IN0(LOW)}}$	1.0	2.0	4.0	kHz
Input PWM clock high frequency detection range on IN0 ⁽³⁵⁾	$f_{\text{IN0(HIGH)}}$	100	200	400	kHz
Output PWM frequency range	f_{PWM}	–	–	1.0	kHz
Output PWM frequency accuracy using calibrated oscillator	$A_{\text{FPWM(CAL)}}$	-10	–	+10	%
Default output PWM frequency using internal oscillator	$f_{\text{PWM(0)}}$	84	120	156	Hz
$\overline{\text{CS}}$ calibration low minimum time detection range	$t_{\text{CSB(MIN)}}$	14	20	26	μs
$\overline{\text{CS}}$ calibration low maximum time detection range	$t_{\text{CSB(MAX)}}$	140	200	260	μs
Output PWM duty-cycle range for $f_{\text{PWM}} = 400\text{ Hz}$ ⁽³⁶⁾	R_{PWM_400}	10	–	98	%
Output PWM duty-cycle range for $f_{\text{PWM}} = 200\text{ Hz}$ ⁽³⁶⁾	R_{PWM_200}	5.0	–	98	%
Output PWM duty-cycle range for $f_{\text{PWM}} = 1.0\text{ kHz}$ for high speed slew rate ⁽³⁶⁾	$R_{\text{PWM}_1\text{k}}$	6.0	–	94	%

INPUT TIMING

Direct input toggle timeout	t_{IN}	175	250	325	ms
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AUTORETRY TIMING

Autoretry period	t_{AUTO}	105	150	195	ms
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Notes

35. Clock fail detector available for PWM_en bit is set to logic [1] and CLOCK_sel is set to logic [0].
36. The PWM ratio is measured at $V_{\text{HS}} = 50\%$ of V_{PWR} and for the default SR value. It is possible to put the device fully-on (PWM duty-cycle 100 %) and fully-off (duty-cycle 0 %). For values outside this range, a calibration is needed between the PWM duty-cycle programming and the PWM on the output with $R_{\text{L}} = 5.0\ \Omega$ resistive load.

Table 6. Dynamic electrical characteristics (continued)

Characteristics noted under conditions $6.0\text{ V} \leq V_{\text{PWR}} \leq 20\text{ V}$, $3.0\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}$, $-40\text{ }^\circ\text{C} \leq T_{\text{A}} \leq 125\text{ }^\circ\text{C}$, $\text{GND} = 0\text{ V}$, unless otherwise noted. Typical values noted reflect the approximate parameter means at $T_{\text{A}} = 25\text{ }^\circ\text{C}$ under nominal conditions, unless otherwise noted.

Characteristic	Symbol	Min	Typ	Max	Unit
TEMPERATURE ON THE GND FLAG					
Thermal prewarning detection ⁽³⁷⁾	T_{OTWAR}	110	125	140	$^\circ\text{C}$
Analog temperature feedback at $T_{\text{A}} = 25\text{ }^\circ\text{C}$ with $R_{\text{CSNS}} = 2.5\text{ k}\Omega$	T_{FEED}	1.15	1.20	1.25	V
Analog temperature feedback derating with $R_{\text{CSNS}} = 2.5\text{ k}\Omega$ ⁽³⁸⁾	DT_{FEED}	-3.5	-3.7	-3.9	$\text{mV}/^\circ\text{C}$
SPI INTERFACE CHARACTERISTICS⁽³⁷⁾					
Maximum frequency of SPI operation	f_{SPI}	–	–	8.0	MHz
Required low state duration for $\overline{\text{RST}}$ ⁽³⁹⁾	t_{WRST}	10	–	–	μs
Rising edge of $\overline{\text{CS}}$ to falling edge of $\overline{\text{CS}}$ (required setup time) ⁽⁴⁰⁾	$t_{\overline{\text{CS}}}$	–	–	1.0	μs
Rising edge of $\overline{\text{RST}}$ to falling edge of $\overline{\text{CS}}$ (required setup time) ⁽⁴⁰⁾	t_{ENBL}	–	–	5.0	μs
Falling edge of $\overline{\text{CS}}$ to rising edge of SCLK (required setup time) ⁽⁴⁰⁾	t_{LEAD}	–	–	500	ns
Required high state duration of SCLK (required setup time) ⁽⁴⁰⁾	t_{WSCLKh}	–	–	50	ns
Required low state duration of SCLK (required setup time) ⁽⁴⁰⁾	t_{WSCLKl}	–	–	50	ns
Falling edge of SCLK to rising edge of $\overline{\text{CS}}$ (required setup time) ⁽⁴⁰⁾	t_{LAG}	–	–	60	ns
SI to falling edge of SCLK (required setup time) ⁽⁴¹⁾	$t_{\text{SI(SU)}}$	–	–	37	ns
Falling edge of SCLK to SI (required setup time) ⁽⁴¹⁾	$t_{\text{SI(HOLD)}}$	–	–	49	ns
SO rise time • $C_{\text{L}} = 80\text{ pF}$	t_{RSO}	–	–	13	ns
SO fall time • $C_{\text{L}} = 80\text{ pF}$	t_{FSO}	–	–	13	ns
SI, $\overline{\text{CS}}$, SCLK, incoming signal rise time ⁽⁴¹⁾	t_{RSI}	–	–	13	ns
SI, $\overline{\text{CS}}$, SCLK, incoming signal fall time ⁽⁴¹⁾	t_{FSI}	–	–	13	ns
Time from rising edge of SCLK to SO low logic level ⁽⁴²⁾	$t_{\text{SO(EN)}}$	–	–	60	ns
Time from rising edge of SCLK to SO high logic level ⁽⁴³⁾	$t_{\text{SO(DIS)}}$	–	–	60	ns

Notes

37. Parameters guaranteed by design.
38. Value guaranteed per statistical analysis
39. $\overline{\text{RST}}$ low duration measured with outputs enabled and going to OFF or disabled condition.
40. Maximum setup time required for the 35XS3400 is the minimum guaranteed time needed from the microcontroller.
41. Rise and fall time of incoming SI, $\overline{\text{CS}}$, and SCLK signals suggested for design consideration to prevent the occurrence of double pulsing.
42. Time required for output status data to be available for use at SO. 1.0 k Ω on pull-up on $\overline{\text{CS}}$.
43. Time required for output status data to be terminated at SO. 1.0 k Ω on pull-up on $\overline{\text{CS}}$.

5.4 Timing diagrams

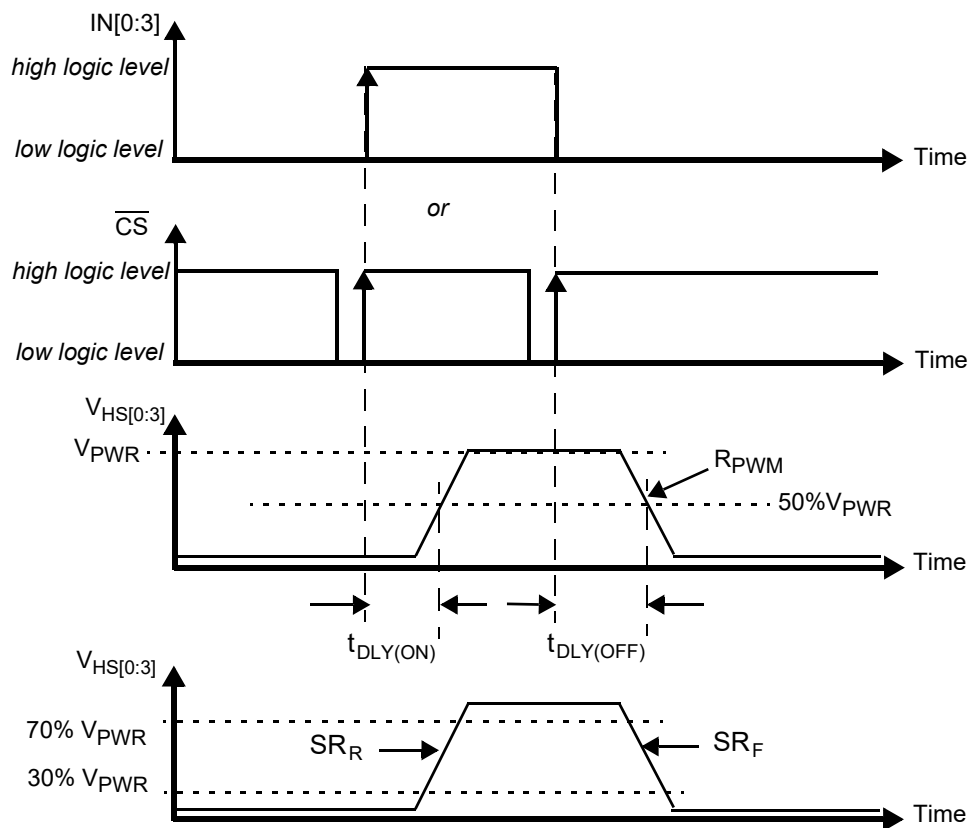


Figure 4. Output slew rate and time delays

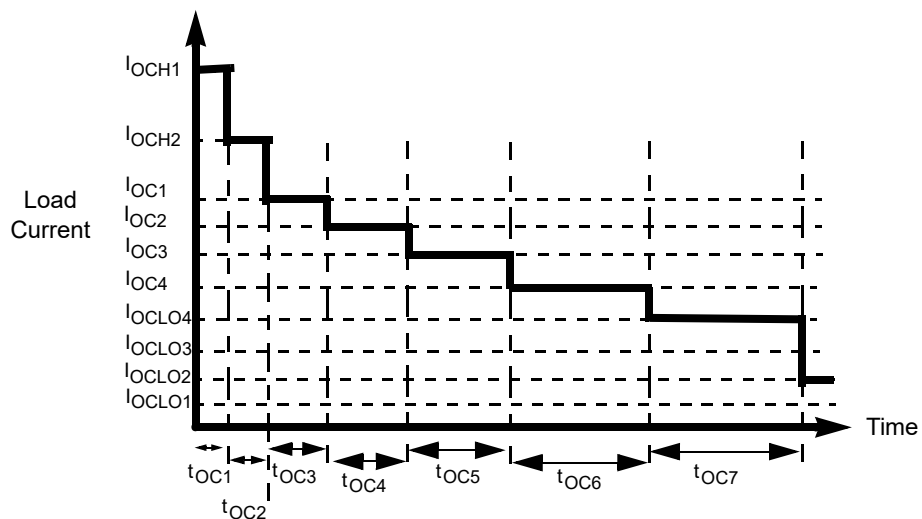


Figure 5. Overcurrent shutdown protection

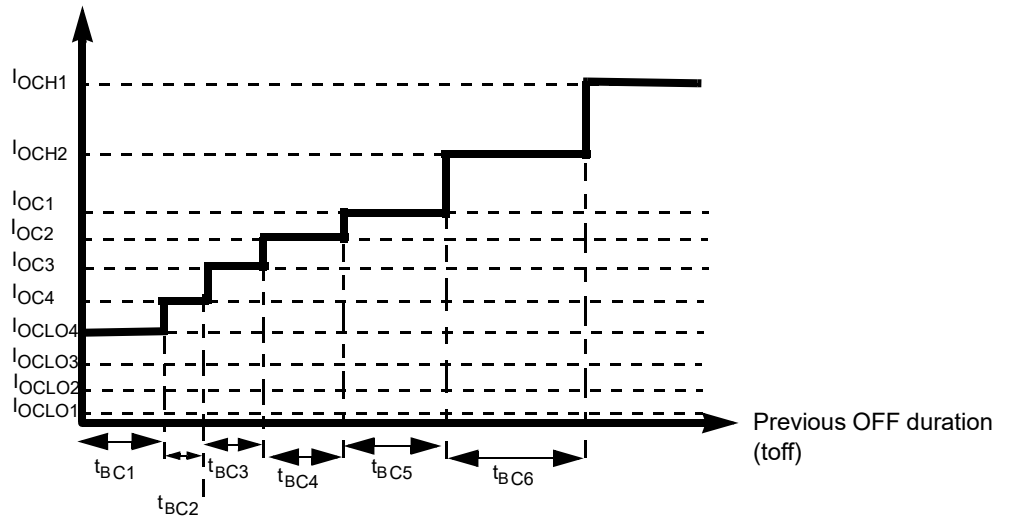


Figure 6. Bulb cooling management

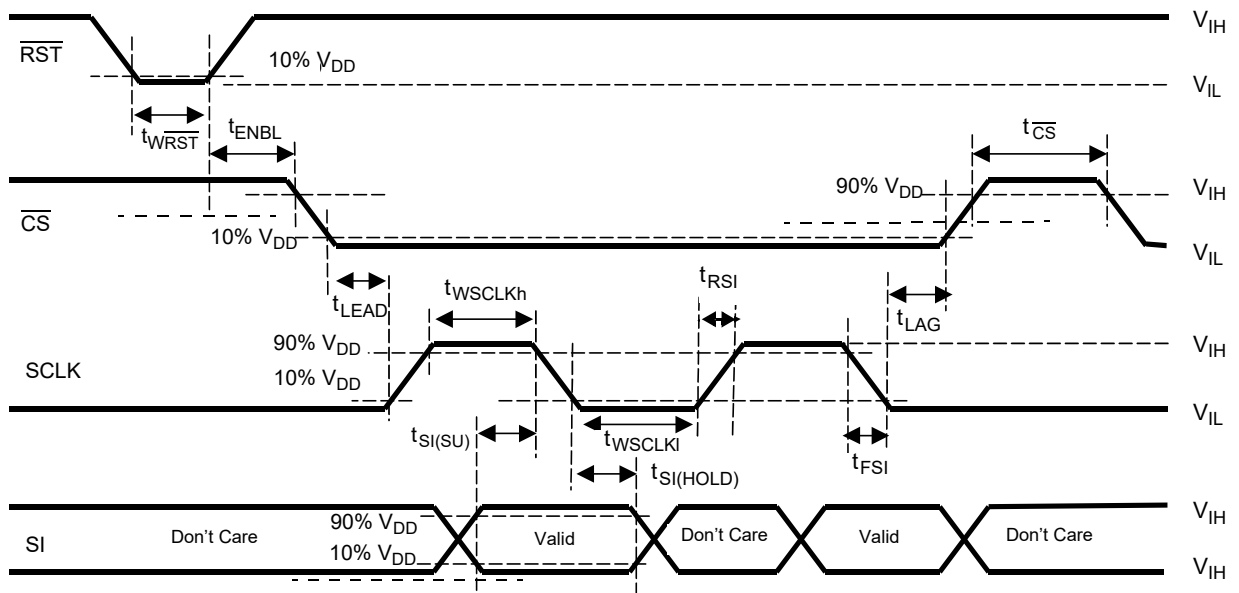


Figure 7. Input timing switching characteristics

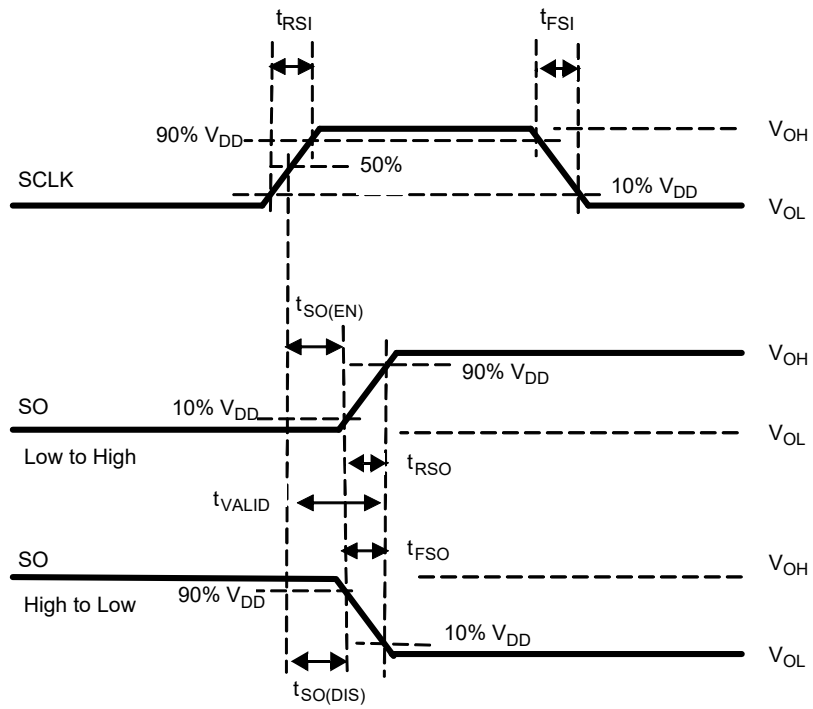


Figure 8. SCLK waveform and valid SO data delay time

6 Functional description

6.1 Introduction

The 35XS3400 is one in a family of devices designed for low-voltage automotive lighting applications. Its four low $R_{DS(on)}$ MOSFETs (quad 35 m Ω) can control four separate 28 W bulbs.

Programming, control and diagnostics are accomplished using a 16-bit SPI interface. Its output with selectable slew-rate improves electromagnetic compatibility (EMC) behavior. Additionally, each output has its own parallel input or SPI control for pulse-width modulation (PWM) control if desired. The 35XS3400 allows the user to program via the SPI the fault current trip levels and duration of acceptable lamp inrush. The device has Fail-safe mode to provide functionality of the outputs in case of MCU damage.

6.2 Functional pin description

6.2.1 Output current monitoring (CSNS)

The Current Sense pin provides a current proportional to the designated HS0:HS3 output or a voltage proportional to the temperature on the GND flag. That current is fed into a ground-referenced resistor (4.7 k Ω typical) and its voltage is monitored by an MCU's A/D. The output type is selected via the SPI. This pin can be tri-stated through the SPI.

6.2.2 Direct inputs (IN0, IN1, IN2, IN3)

Each IN input wakes the device. The IN0:IN3 high-side input pins are also used to directly control HS0:HS3 high-side output pins. If the outputs are controlled by the PWM module, the external PWM clock is applied to IN0 pin. These pins are to be driven with CMOS levels, and they have a passive internal pull-down, R_{DWN} .

6.2.3 Fault status (\overline{FS})

This pin is an open drain configured output requiring an external pull-up resistor to V_{DD} for fault reporting. If a device fault condition is detected, this pin is active LOW. Specific device diagnostics and faults are reported via the SPI SO pin.

6.2.4 Wake

The wake input wakes the device. An internal clamp protects this pin from high damaging voltages with a series resistor (10 k Ω typ). This input has a passive internal pull-down, R_{DWN} .

6.2.5 Reset (\overline{RST})

The reset input wakes the device. This is used to initialize the device configuration and fault registers, as well as place the device in a low-current Sleep mode. The pin also starts the watchdog timer when transitioning from logic [0] to logic [1]. This pin has a passive internal pull-down, R_{DWN} .

6.2.6 Chip select (\overline{CS})

The \overline{CS} pin enables communication with the master microcontroller (MCU). When this pin is in a logic [0] state, the device is capable of transferring information to, and receiving information from, the MCU. The 35XS3400 latches in data from the input shift registers to the addressed registers on the rising edge of \overline{CS} . The device transfers status information from the power output to the Shift register on the falling edge of \overline{CS} . The SO output driver is enabled when \overline{CS} is logic [0]. \overline{CS} should transition from a logic [1] to a logic [0] state only when SCLK is a logic [0]. \overline{CS} has an active internal pull-up from V_{DD} , I_{UP} .

6.2.7 Serial clock (SCLK)

The SCLK pin clocks the internal shift registers of the 35XS3400 device. The serial input (SI) pin accepts data into the input shift register on the falling edge of the SCLK signal while the serial output (SO) pin shifts data information out of the SO line driver on the rising edge of the SCLK signal. It is important the SCLK pin be in a logic low state whenever \overline{CS} makes any transition. For this reason, it is recommended the SCLK pin be in a logic [0] whenever the device is not accessed (\overline{CS} logic [1] state). SCLK has an active internal pull-down. When \overline{CS} is logic [1], signals at the SCLK and SI pins are ignored and SO is tri-stated (high-impedance) (see [Figure 10](#), page [23](#)). SCLK input has an active internal pull-down, I_{DWN} .

6.2.8 Serial input (SI)

This is a serial interface (SI) command data input pin. Each SI bit is read on the falling edge of SCLK. A 16-bit stream of serial data is required on the SI pin, starting with D15 (MSB) to D0 (LSB). The internal registers of the 35XS3400 are configured and controlled using a 5-bit addressing scheme described in [Table 11](#), page [33](#). Register addressing and configuration are described in [Table 12](#), page [33](#). SI input has an active internal pull-down, I_{DWN} .

6.2.9 Digital drain voltage (VDD)

This pin is an external voltage input pin used to supply power to the SPI circuit. In the event V_{DD} is lost (V_{DD} Failure), the device goes to Fail-safe mode.

6.2.10 Ground (GND)

These pins are the ground for the device.

6.2.11 Positive power supply (VPWR)

This pin connects to the positive power supply and is the source of operational power for the device. The VPWR contact is the backside surface mount tab of the package.

6.2.12 Serial output (SO)

The SO data pin is a tri-stateable output from the shift register. The SO pin remains in a high-impedance state until the \overline{CS} pin is put into a logic [0] state. The SO data is capable of reporting the status of the output, the device configuration, the state of the key inputs, etc. The SO pin changes state on the rising edge of SCLK and reads out on the falling edge of SCLK. SO reporting descriptions are provided in [Table 24](#), page [38](#).

6.2.13 High-side outputs (HS3, HS1, HS0, HS2)

Protected 35 m Ω high-side power outputs to the load.

6.2.14 Fail-safe input (FSI)

This pin incorporates an active internal pull-up current source from internal supply (V_{REG}). This enables the watchdog timeout feature. When the FSI pin is opened, the watchdog circuit is enabled. After a watchdog timeout occurs, the output states depends on IN[0:3]. When the FSI pin is connected to GND, the watchdog circuit is disabled. The output states depends on IN[0:3] in case of V_{DD} failure condition, in case V_{DD} failure detection is activated (VDD_FAIL_en bit sets to logic [1]).

6.3 Functional internal block description

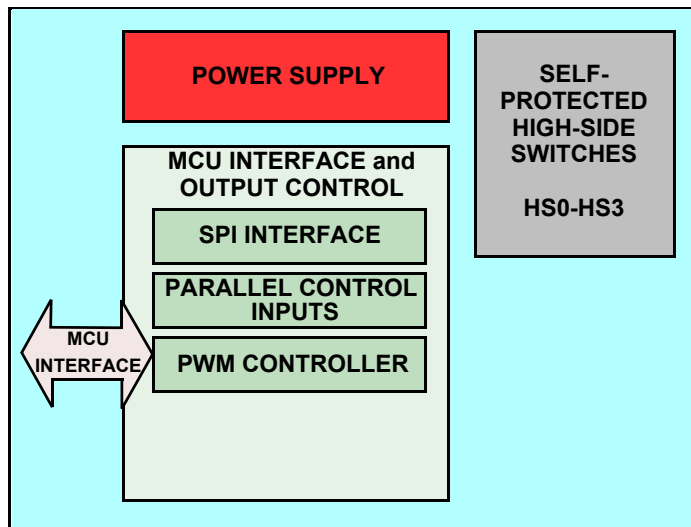


Figure 9. Functional block diagram

6.3.1 Power supply

The 35XS3400 is designed to operate from 4.0 to 28 V on the VPWR pin. Characteristics are provided from 6.0 to 20 V for the device. The VPWR pin supplies power to internal regulator, analog, and logic circuit blocks. The VDD supply is used for Serial Peripheral Interface (SPI) communication in order to configure and diagnose the device. This IC architecture provides a low quiescent current Sleep mode. Applying V_{PWR} and V_{DD} to the device will place the device in the Normal mode. The device will transit to Fail-safe mode in case of failures on the SPI or/and on the V_{DD} voltage.

6.3.2 High-side switches: HS0 – HS3

These pins are the high-side outputs controlling automotive lamps located for the rear of vehicle, such as 28 W bulbs and LED modules. 55 W/65 W lamps can be driven for two outputs shorted together. Those N-channel MOSFETs with 35 mΩ $R_{DS(on)}$ are self-protected and present extended diagnostics in order to detect bulb outage and short-circuit fault condition. The HS output is actively clamped during turn off of inductive loads and inductive battery line.

When driving DC motor or solenoid loads demanding multiple switching, an external recirculation device must be used to maintain the device in its safe operating area.

6.3.3 MCU interface and output control

In Normal mode, each bulb is controlled directly from the MCU through SPI. A pulse width modulation control module allows improvement of lamp lifetime with bulb power regulation (PWM frequency range from 100 to 400 Hz) and addressing the dimming application (day running light). An analog feedback output provides a current proportional to the load current or the temperature of the board. The SPI is used to configure and to read the diagnostic status (faults) of high-side outputs. The reported fault conditions are: OpenLoad, short-circuit to battery, short-circuit to ground (overcurrent and severe short-circuit), thermal shutdown, and under/overvoltage. Due to accurate and configurable overcurrent detection circuitry and wire-harness optimization, the vehicle is lighter.

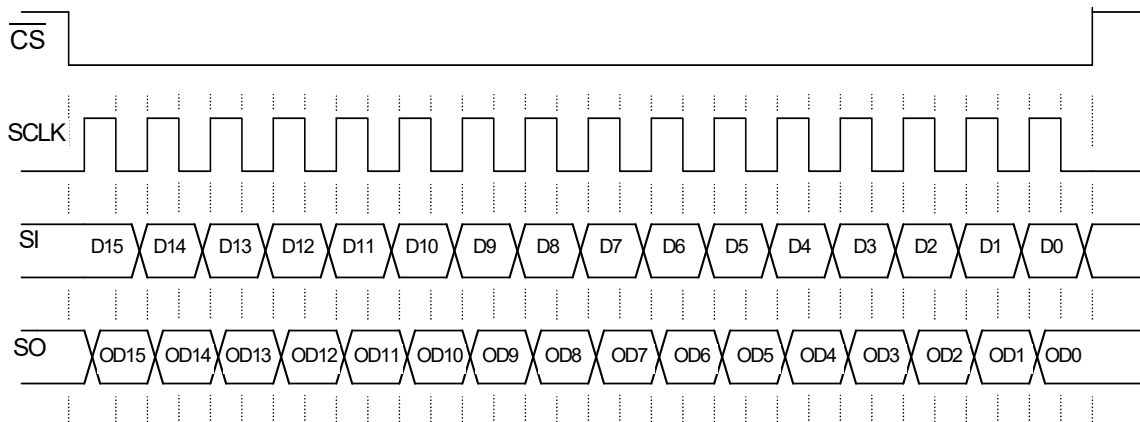
In Fail-safe mode, each lamp is controlled with dedicated parallel input pins. The device is configured in default mode.

7 Functional device operation

7.1 SPI protocol description

The SPI interface has a full duplex, three-wire synchronous data transfer with four I/O lines associated with it: Serial Input (SI), Serial Output (SO), Serial Clock (SCLK), and Chip Select (\overline{CS}).

The SI/SO pins of the 35XS3400 follow a first-in first-out (D15 to D0) protocol, with both input and output words transferring the most significant bit (MSB) first. All inputs are compatible with 5.0 V or 3.3 V CMOS logic levels.



- Notes
1. \overline{RST} is a logic [1] state during the above operation.
 2. D15:D0 relate to the most recent ordered entry of data into the device.
 3. OD15:OD0 relate to the first 16 bits of ordered fault and status data out of the device.

Figure 10. Single 16-bit word SPI communication

7.2 Operational modes

The 35XS3400 has four operating modes: Sleep, Normal, Fail-safe and Fault. [Table 7](#) and [Figure 12](#) summarize details contained in succeeding paragraphs.

The [Figure 11](#) describes an internal signal called IN_ON[x] depending on IN[x] input.

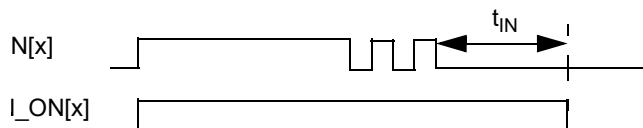


Figure 11. IN_ON[x] internal signal

The 35XS3400 transits to operating modes according to the following signals:

- wake-up = $\overline{\text{RST}}$ or WAKE or IN_ON[0] or IN_ON[1] or IN_ON[2] or IN_ON[3],
- fail = (V_{DD} Failure and VDD_FAIL_en) or (Watchdog time-out and FSI input not shorted to ground),
- fault = OC[0:3] or OT[0:3] or SC[0:3] or UV (UV) or (OV and OV_dis).

Table 7. 35XS3400 operating modes

Mode	wake-up	fail	fault	Comments
Sleep	0	x	x	Device is in Sleep mode. All outputs are OFF.
Normal	1	0	0	Device is currently in Normal mode. Watchdog is active if enabled.
Fail-safe	1	1	0	Device is currently in Fail-safe mode due to watchdog timeout or V_{DD} Failure conditions. The output states depend on the corresponding input in case FSI is open.
Fault	1	X	1	Device is currently in Fault mode. The faulted output(s) is (are) OFF. The safe autoretry circuitry is active to turn-on again the output(s).

x = Don't care.

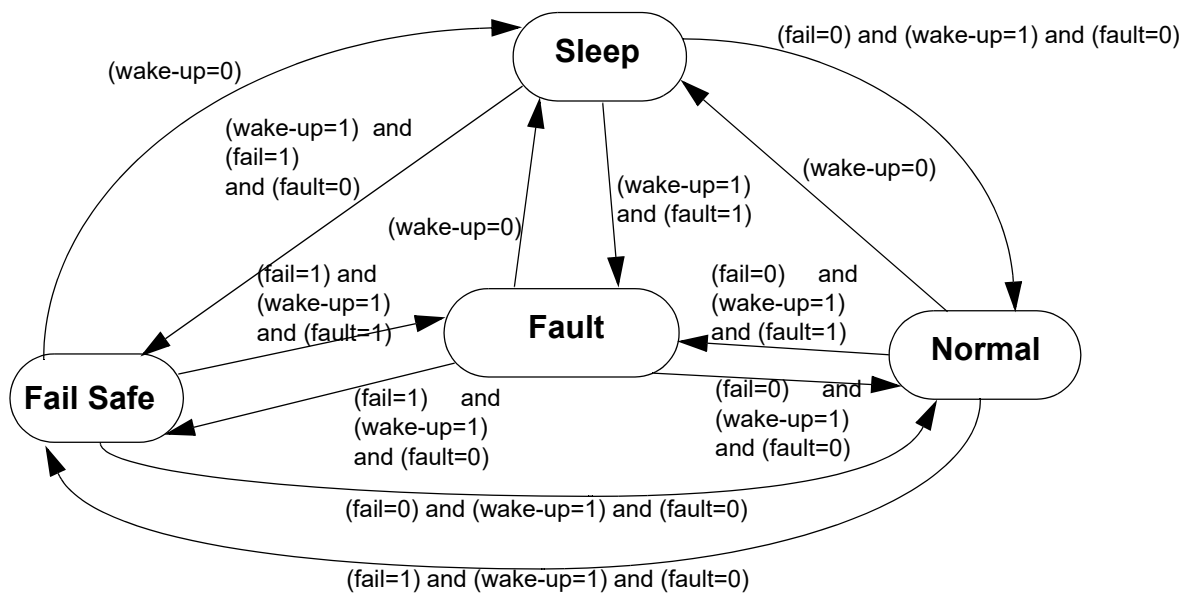


Figure 12. Operating modes

7.2.1 Sleep mode

The 35XS3400 is in Sleep mode when:

- V_{PWR} and V_{DD} are within the normal voltage range,
- wake-up = 0,
- fail = X,
- fault = X.

This is the Default mode of the device after first applying battery voltage (V_{PWR}) prior to any I/O transitions. This is also the state of the device when the WAKE and $\overline{\text{RST}}$ and IN_ON[0:3] are logic [0]. In the Sleep mode, the output and all unused internal circuitry, such as the internal regulator, are off to minimize draw current. In addition, all SPI-configurable features of the device are as if set to logic [0].

7.2.2 Normal mode

The 35XS3400 is in Normal mode when:

- V_{PWR} and V_{DD} are within the normal voltage range,
- wake-up = 1,
- fail = 0,
- fault = 0.

In this mode, the NM bit is set to $\overline{\text{Ifault_contrologic}}$ [1] and the outputs HS[0:3] are under control, as defined by hson signal:

$\text{hson}[x] = ((\text{IN}[x] \text{ and } \overline{\text{DIR_dis}}[x]) \text{ or } \text{On bit}[x]) \text{ and } \overline{\text{PWM_en}}$ or $(\text{On bit}[x] \text{ and } \text{Duty_cycle}[x] \text{ and } \overline{\text{PWM_en}})$.

In this mode and also in Fail-safe, the fault condition reset depends on $\overline{\text{fault_control}}$ signal, as defined below:

$\overline{\text{fault_control}}[x] = ((\text{IN_ON}[x] \text{ and } \overline{\text{DIR_dis}}[x]) \text{ and } \overline{\text{PWM_en}}$) or $(\text{On bit}[x])$.

7.2.2.1 Programmable PWM module

The outputs HS[0:3] are controlled by the programmable PWM module if PWM_en and On bits are set to logic [1].

The clock frequency from IN0 input pin or from internal clock is the factor 2^7 (128) of the output PWM frequency (CLOCK_sel bit). The outputs HS[0:3] can be controlled in the range of 5% to 98% with a resolution of 7 bits of duty-cycle ([Table 8](#)). The state of other IN pin is ignored.

Table 8. Output PWM resolution

On bit	Duty-cycle	Output state
0	X	OFF
1	0000000	PWM (1/128 duty-cycle)
1	0000001	PWM (2/128 duty-cycle)
1	0000010	PWM (3/128 duty-cycle)
1	n	PWM ((n+1)/128 duty-cycle)
1	1111111	fully ON

The timing includes seven programmable PWM switching delay (number of PWM clock rising edges) to improve overall EMC behavior of the light module ([Table 9](#)).